

# Femtosecond Laser Ablation of a Solid Tin Target

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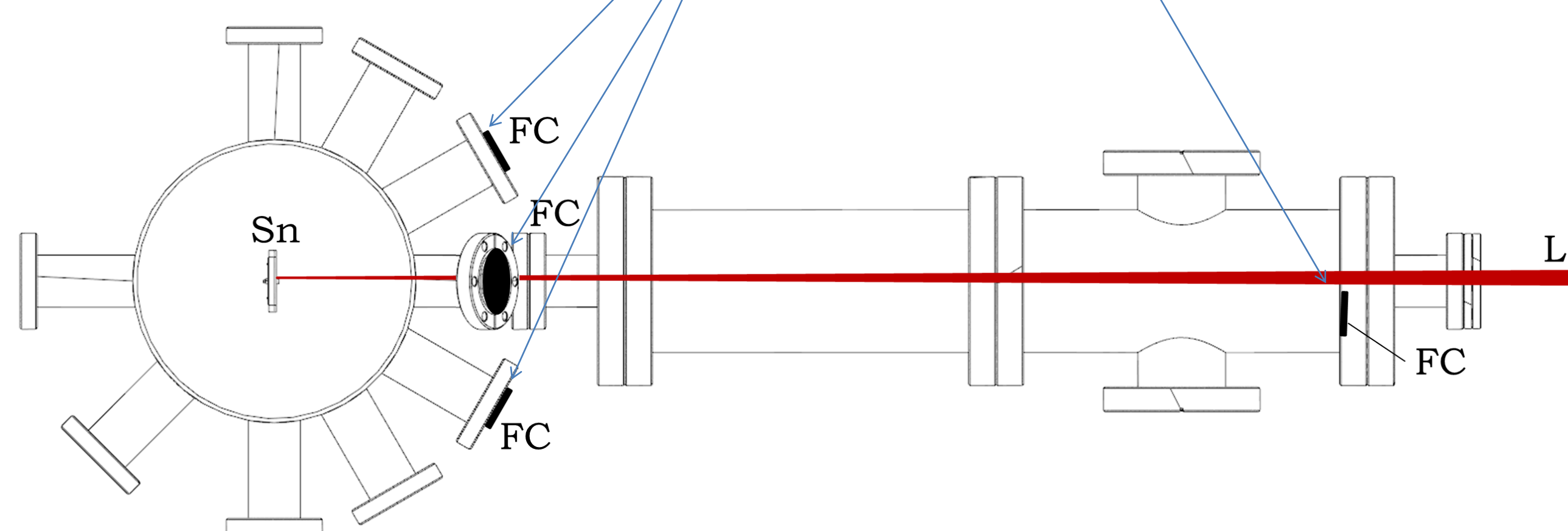
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**Synopsis** The results of a study on femtosecond laser ablation of a solid tin target are presented. We show the ion yield and energy distributions, the angular distribution, and the ablation depth for the pulse length and pulse energy.

## Experimental Setup

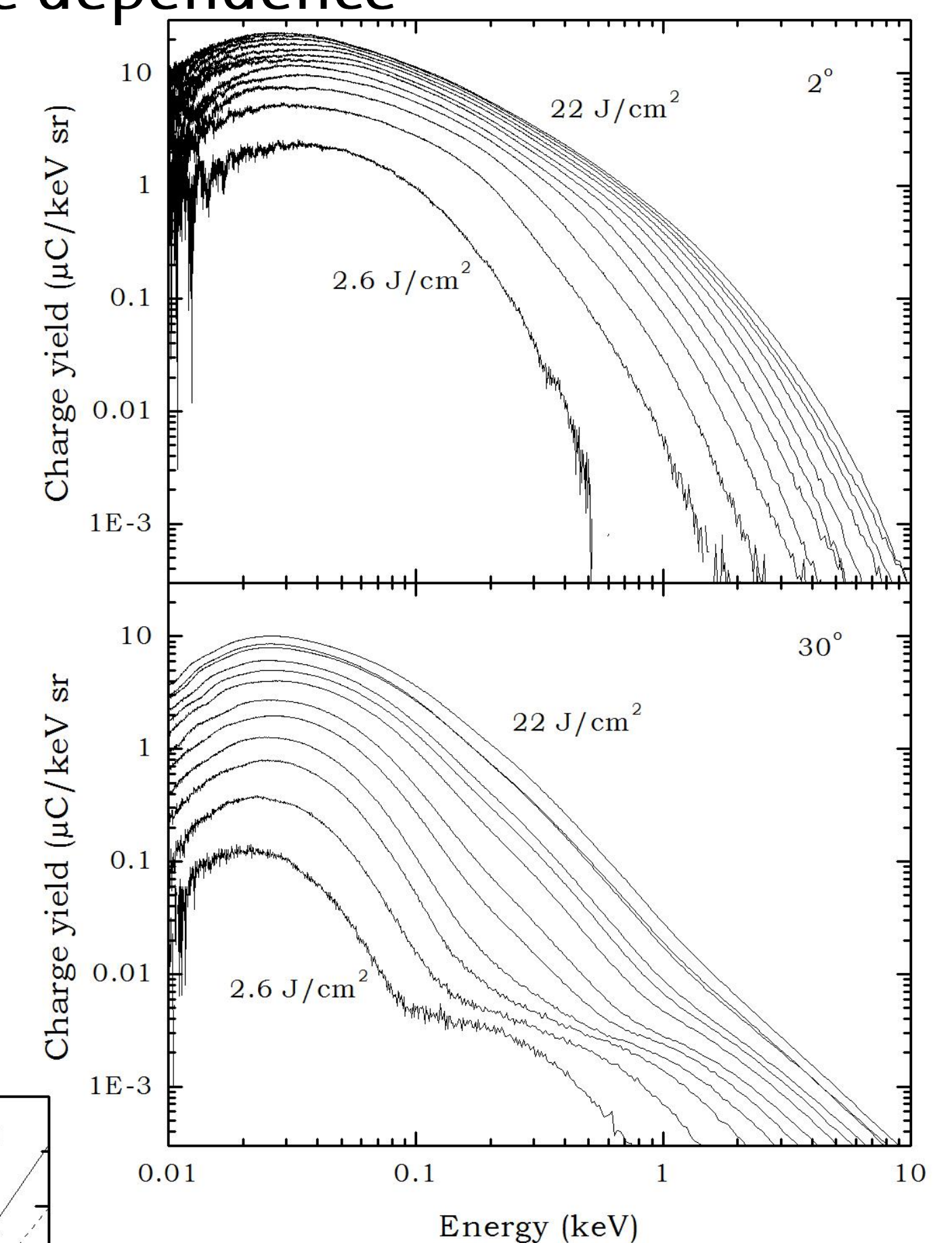
- Laser: 800 nm pulses at effective rate of 5 Hz
- Target: planar solid Sn target
- A Faraday Cup (FC) at 2° (at 70 cm) and three FCs at 30 degrees (at 24 and 26 cm) to measure ion distributions.



## Peak fluence dependence

Majority of ions have low energy (up to 100 eV), more high-energy ions for higher fluences.

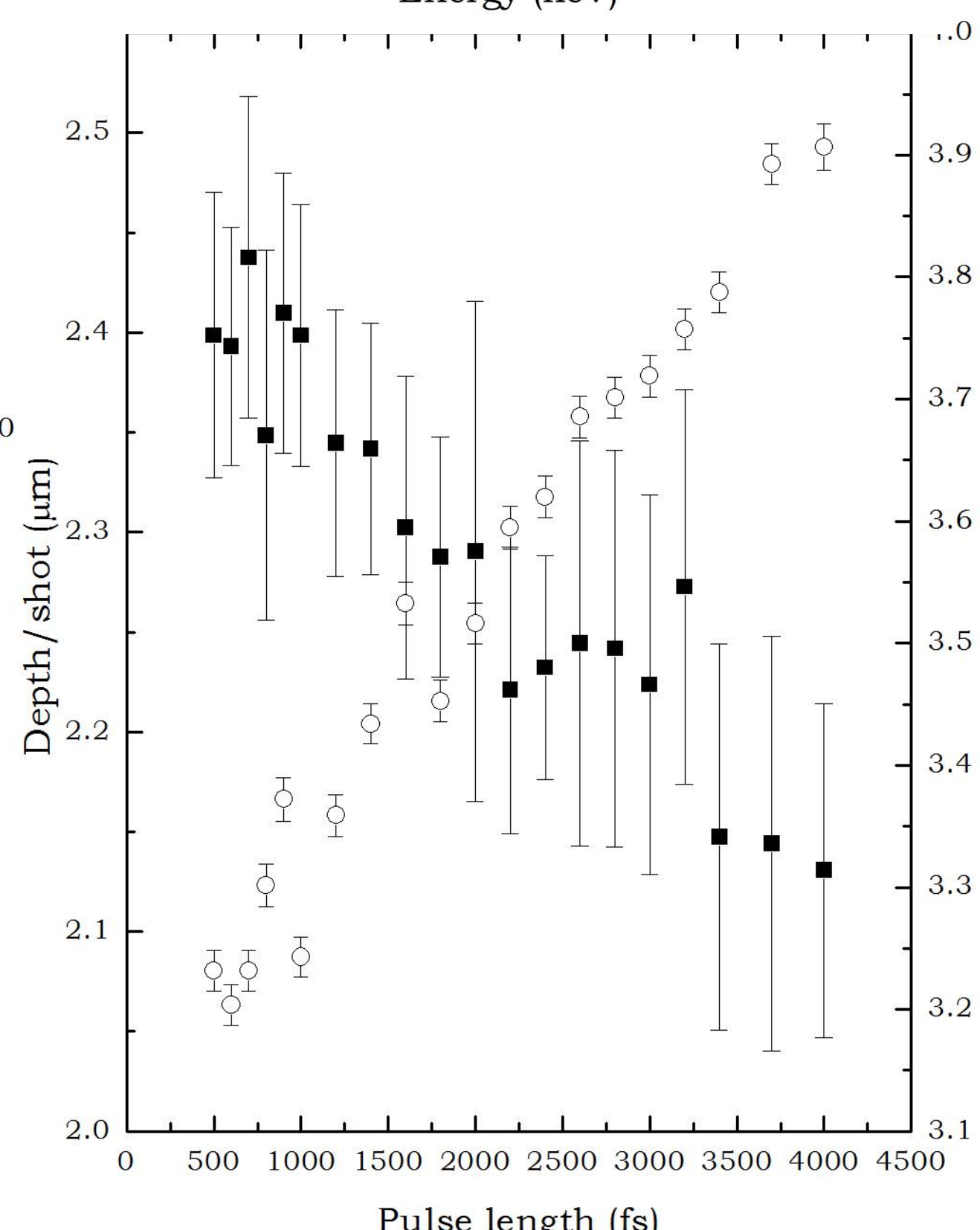
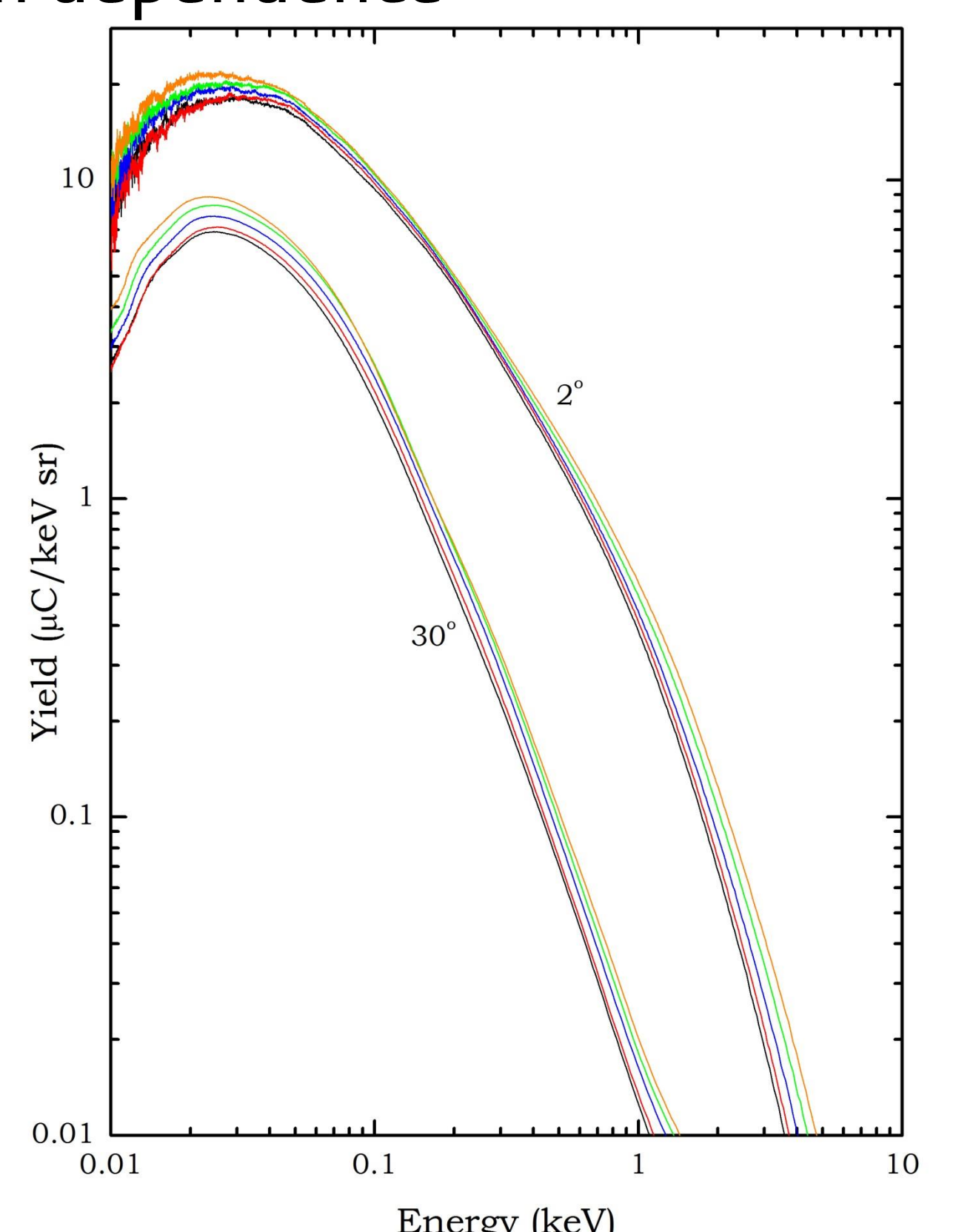
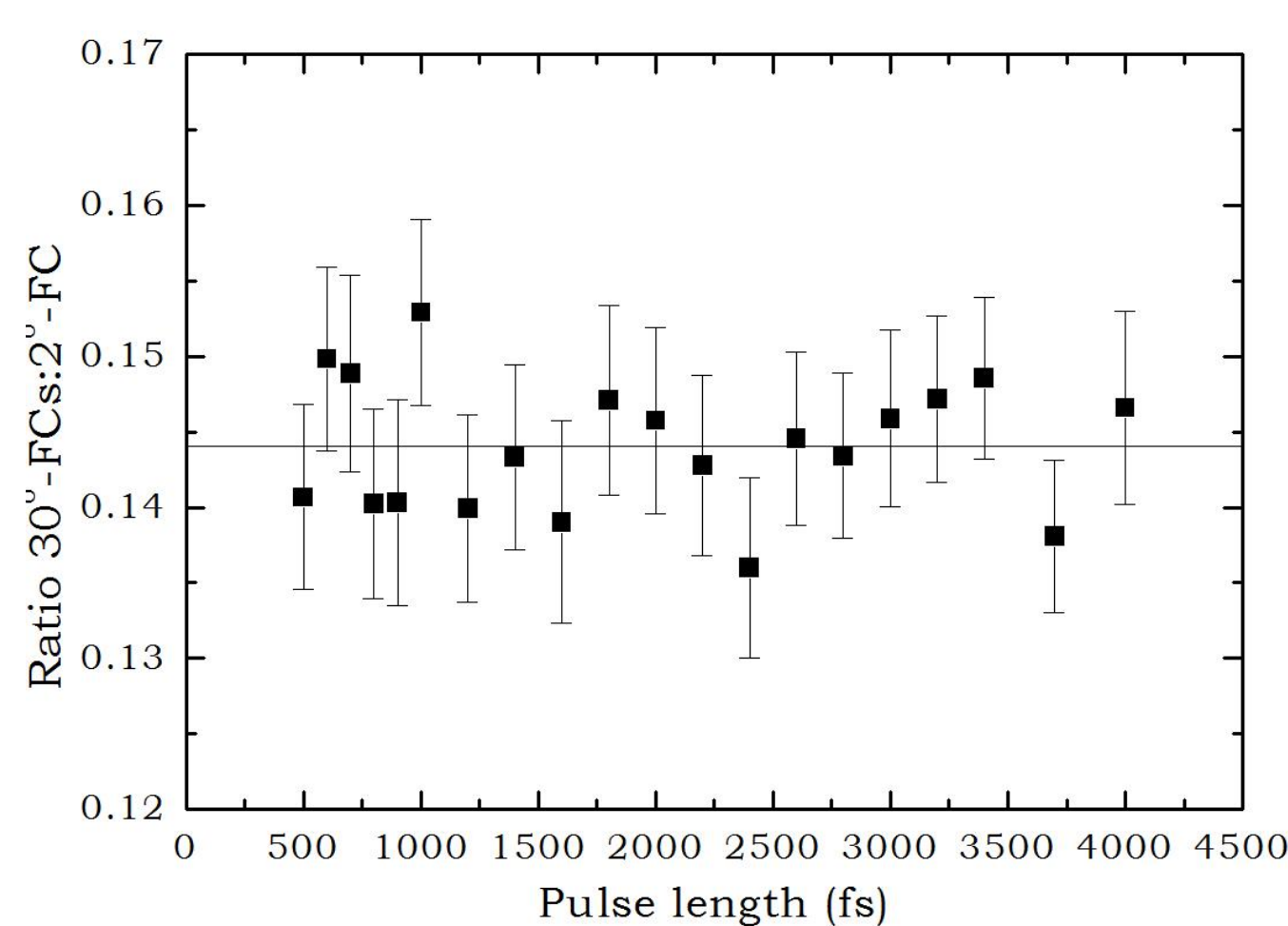
Additional high-energy peak is visible, but indistinguishable at higher fluences and 2°.



## Pulse length dependence

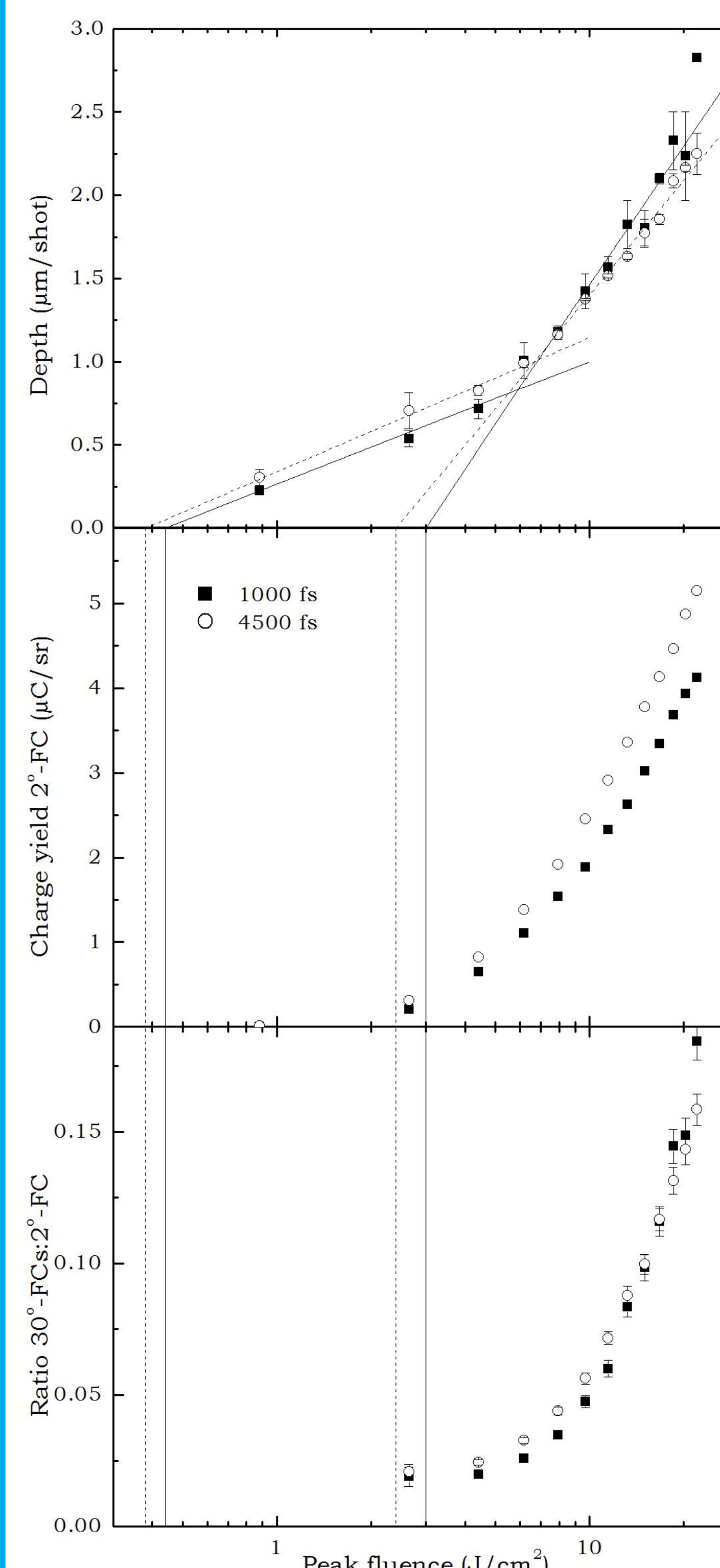
More ions for all energies at longer pulse lengths, especially high-energy ions

Constant ratio yields: angular distribution is not dependent on pulse length.



Yield increases with 30% while ablation depth decreases with 10% for this range.

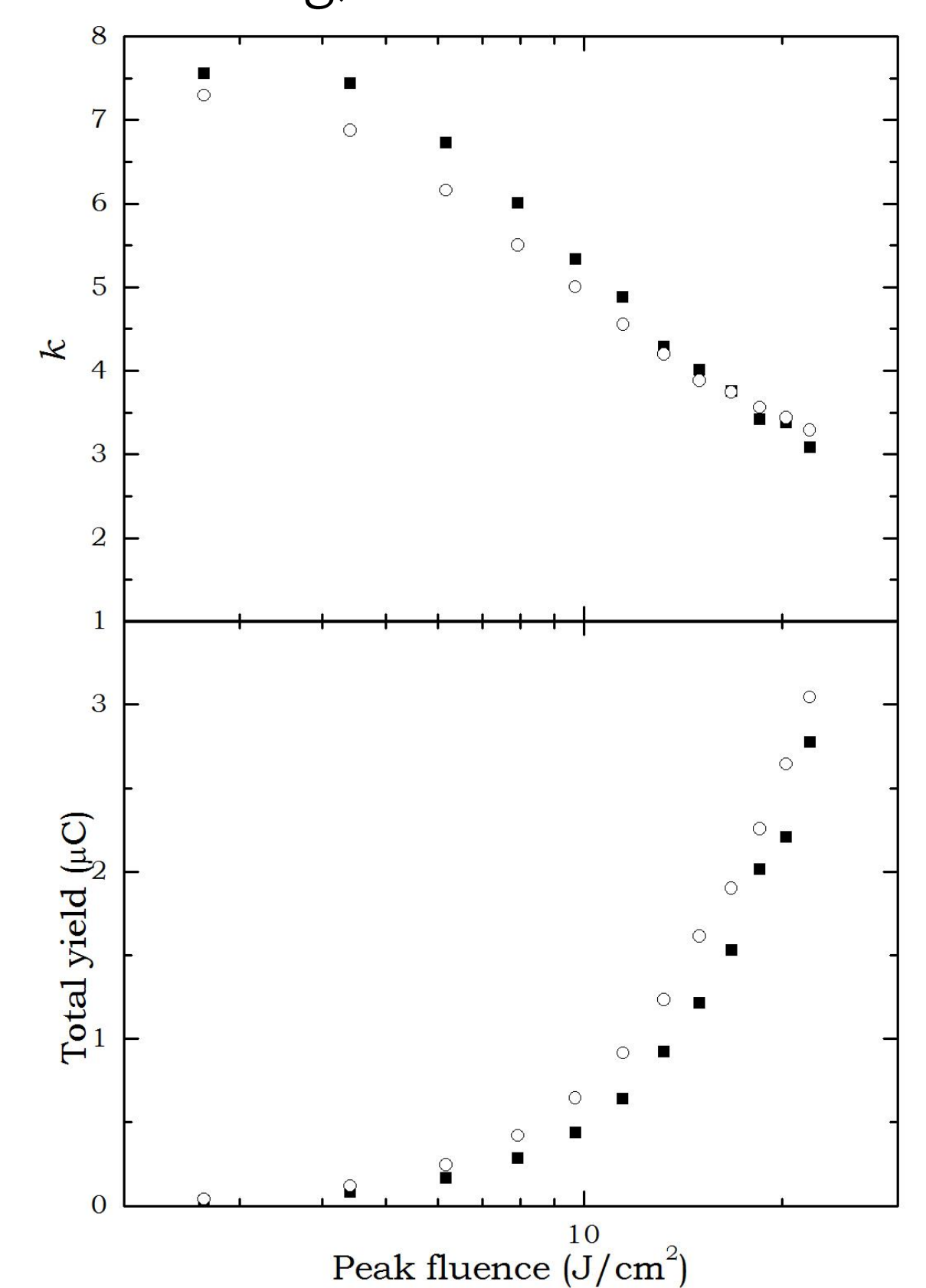
Five pulse lengths are shown: 500 fs (black), 1200 fs (red), 2000 fs (blue), 3000 fs (green) and 4000 fs (orange).



Ablation depth has two-region logarithmic dependence with fairly constant ablation threshold:

$$\delta = B \ln \left( \frac{F}{F_{th}} \right)$$

-Yield increases gradually with more ions at 4000 fs  
-The angular distribution is rapidly broadening;



Plasma can be described by: 
$$\frac{Y(\phi)}{Y(0)} = \frac{[1 + \tan^2 \phi]^{3/2}}{[1 + k^2 \tan^2 \phi]^{3/2}}$$

## Conclusions

- The bulk of the ions have low energy, below 100 eV, although the fraction of high-energy ions increases for higher fluences
- The ablation depth has a two-region logarithmic dependence on the fluence. The yield increases gradually and the distribution broadens.
- The ion yield increases for increasing pulse length, while the ablation depth decreases slightly. The angular distribution stays the same.



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